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2D layered transitionmetal dichalcogenides

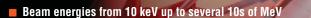
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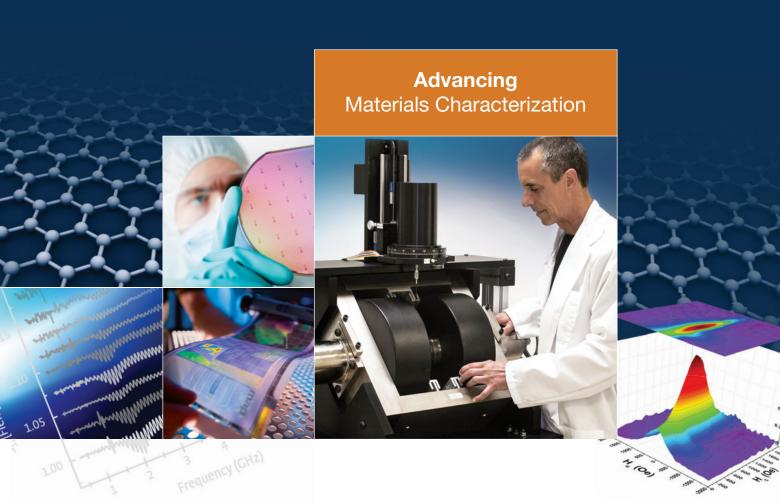


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Energy Quarterly



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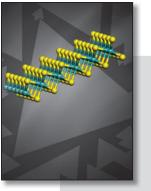
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ON THE COVER

2D layered transition-metal dichalcogenides. This issue of MRS Bulletin provides an overview of two-dimensional layered transitionmetal dichalcogenides (TMDCs), their fundamental materials properties, and their applications in electronics, optoelectronics, and energy. TMDCs are compounds consisting of a transition metal M and chalcogen atoms X (S, Se, Te). The cover shows a schematic of

a single layer of molybdenum disulfide (MoS₂). Courtesy of Seung Soon Jang and Parveen Sood of the Georgia Institute of Technology. The background image shows monolayer MoS₂ grown on a crystalline sapphire substrate, which has been modified for the purpose of this cover. The MoS₂ domains are aligned due to an epitaxial registry with the sapphire substrate. Courtesy of Kehao Zhang, The Pennsylvania State University. See the technical theme that begins on page 558.



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The Materials Research Society (MRS), a not-for-profit scientific association founded in 1973 and headquartered in Warrendale, Pennsylvania, USA, promotes interdisciplinary materials research. Today, MRS is a growing, vibrant, member-driven organization of over 16,000 materials researchers spanning over 80 countries, from academia, industry, and government, and a recognized leader in the advancement of interdisciplinary materials research.

The Society's interdisciplinary approach differs from that of single-discipline professional societies because it promotes information exchange across many scientific and technical fields touching materials development. MRS conducts three major international annual meetings and also sponsors numerous single-topic scientific meetings. The Society recognizes professional and technical excellence and fosters technical interaction through University Chapters. In the international arena, MRS implements bilateral projects with partner organizations to benefit the worldwide materials community. The Materials Research Society Foundation helps the Society advance its mission by supporting various projects and initiatives.

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